SBDB3045CT SCHOTTKY BARRIER RECTIFIER

MAIN CHARACTERISTICS

I_O	30（2×15）A
V_{RRM}	45 V
T_j	150 ℃
$V_{F(typ)}$	0.58V （@Ta=125℃）

TO-263

1.ANODE
2.CATHODE
3.ANODE

FEATURES

- Low Power Loss,High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop

MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{RRM}	Peak repetitive reverse voltage	45	V
V_{RWM}	Working peak reverse voltage		
V_R	DC blocking voltage		
$V_{R(RMS)}$	RMS reverse voltage	31.5	V
I_O	Average rectified output current	30	A
I_{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)	200	A
$R_{\Theta Jc}$	Thermal resistance from junction to case ,Tc=25℃	2.0	℃/W
$R_{\Theta JA}$	Thermal resistance from junction to ambient	62.5	℃/W
T_j	Junction temperature	150	℃
T_{stg}	Storage temperature	-55~+150	℃

ELECTRICAL CHARACTERISTICS (T_a=25℃ unless otherwise specified)

Parameter	Symbol	Test conditions		Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	I_R=0.1mA		45			V
Reverse current	I_R	V_R=45V	Tj =25℃		5.0	100	uA
			Tj =125℃		5.0		mA
Forward voltage	V_F	I_F=10A	Tj =25℃		0.55		V
			Tj =125℃		0.52		V
		I_F=15A	Tj =25℃		0.62	0.70	V
			Tj =125℃		0.58		V

*Pulse test: pulse width ≤300μs, duty cycle≤ 2.0%.

FIG.1: FORWARD CURRENT DERATING CURVE

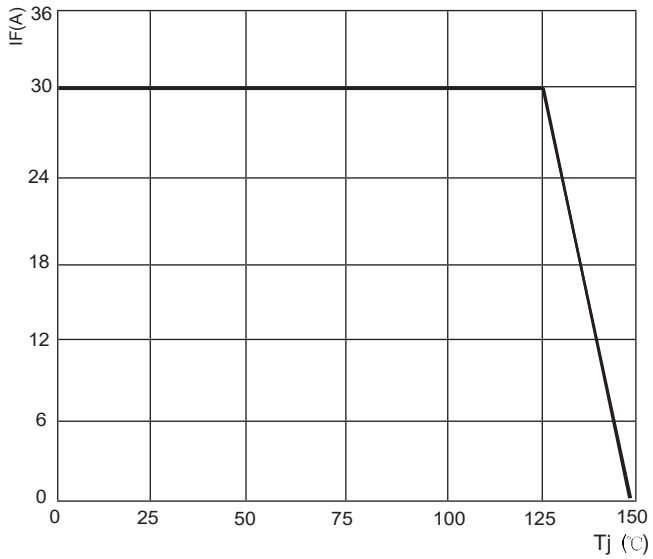

FIG.2: TYPICAL FORWARD CHARACTERISTICS

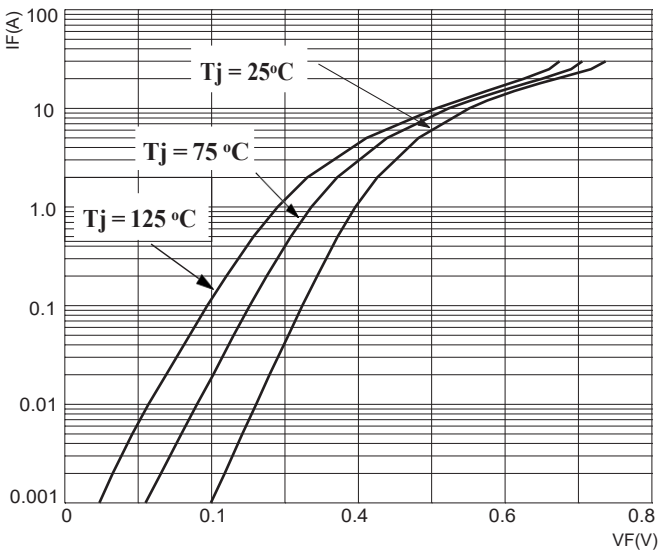

FIG.3: TOTAL CAPACITANCE DERATING CURVE

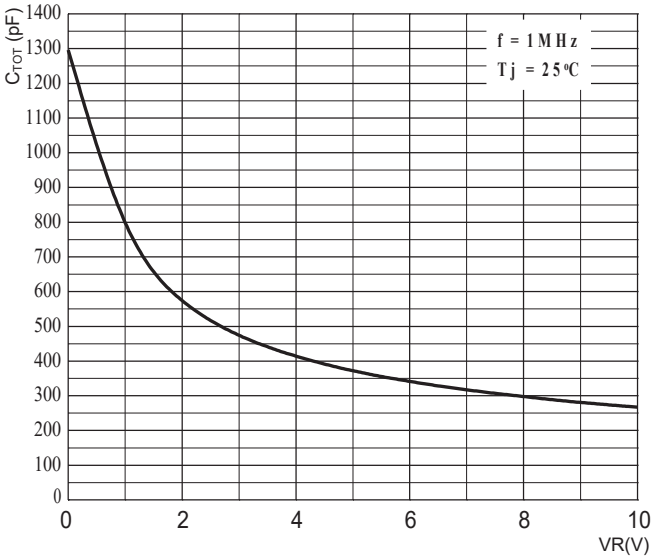

FIG.4: TYPICAL REVERSE CHARACTERISTICS